NSN 5961-01-344-4417 Unitized Semiconductor Devices - Page 1 of 1



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nclosure Material:
Metal
Overall Length:
Between 0.690 inches and 0.770 inches
Terminal Length:
Between 0.150 inches and 0.230 inches
Overall Height:
Between 0.080 inches and 0.120 inches
Overall Width:
Between 0.280 inches and 0.310 inches
Component Name And Quantity:
4 transistor
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
100.0 drain to source voltage all transistor and 100.0 drain to gate voltage all transistor and 20.0 gate to source voltage all transistor
Current Rating Per Characteristic:
4.00 amperes off-state current, peak all transistor and 1.00 amperes drain current all transistor
Power Rating Per Characteristic:
2.5 watts total device dissipation all transistor
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Terminal Type And Quantity:
14 pin
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Filg:
A110a0